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Vinylene-Bridged Difluorobenzo[c][1,2,5]-thiadiazole (FBTzE): A New Electron-Deficient Building Block for High-Performance Semiconducting Polymers in Organic Electronics

Yuya Asanuma, ^a Hiroki Mori, ^b Ryosuke Takahashi ^a and Yasushi Nishihara ^{b*}

A new class of an acceptor unit, vinylene-bridged 5,6-difluorobenzothiadiazole **FBTzE**, has been developed. Palladiumcatalyzed Migita-Kosugi-Stille coupling reactions of **1** with **2**, yielding **3** and its sequential dehydrogenative coupling with **4**, readily afforded **FBTzE**-containing monomers **5a-5c** that have lower lowest unoccupied molecular orbital (LUMO) energy level and smaller energy gap than those of 5,6-difluorobenzothiadiazole (**DFBT**). Subsequently, three types of **FBTzE**containing copolymers **3T**, **4T**, and **2TTT** were synthesized by Migita-Kosugi-Stille coupling of monomers **5a-5c** with distannylated thiophene, bithiophene, and thienothiophene, respectively and their physicochemical properties and solar cell performances were evaluated. As a result of cyclic voltammogram, the synthesized **FBTzE**-based polymers have deeper highest occupied molecular orbital (HOMO) and LUMO energy levels, and stronger intermolecular interactions than those of **DFBT**-based polymer **PffBT4T-DT**. Although **3T**/PC₆₁BM blended film formed favorable face-on orientation with short d_{π} of 3.57 Å, its solar cell showed poor PCE of 2.7% owing to the construction of large phase separation structure with a domain size over 100 nm. In a sharp contrast, **2TTT**/PC₆₁BM formed unsuitable edge-on orientation with short d_{π} of 3.49 Å, but its film formed optimal nanoscale phase separation, leading to a good performance with PCE of up to 5.2%.

Introduction

Donor-Acceptor (D-A) type semiconducting polymers have been widely utilized for the development of high-performance p-type and n-type semiconductors in organic field-effect transistors (OFETs)^{1,2} and organic photovoltaic cells (OPVs).^{3,4} Main advantages of D-A polymers are electron delocalization and the construction of quinoidal structures through a mesomeric effect, leading to broad absorption with a small bandgap (E_g) and strong intermolecular interactions owing to their electrostatic interaction between polymer mainchains.^{1,3} In addition, the electronic state (highest occupied molecular orbital, (HOMO) and lowest unoccupied molecular orbital (LUMO) energy level) of D-A polymers can easily be controlled by combining the various donor and acceptor units.^{1,3} To date, many researchers have developed the high-performance D-A polymers and achieved high field-effect mobility (μ) over 1 cm² V^{-1} s⁻¹ 6⁻¹¹ and high power conversion efficiency (PCE) over 10%.12-17

polymers and air-stable n-type polymers for OFETs and OPVs, the development of strong acceptor units is highly desirable. developed Among the strong acceptors including (DPP)^{7,18-20}, (IID)²¹⁻²⁴, diketopyrrolopyrrole isoindigo naphthalenediimide (NDI)²⁵⁻²⁷, naphthobisthiadiazole (NTz)^{13,28}, and a double $B \leftarrow N$ bridged bipyridyl (BNBP)²⁹⁻³¹, 5,6difluorobenzo[c][1,2,5]thiadiazole (DFBT, Figure 1) is the wellknown strong acceptor unit for both high-performance OFETs and OPVs, 15, 32-40 because of the following reasons. First, not only the electron-deficient 1,2,5-thidiazole ring and obenzoquinoidal structure of a DFBT core, but also two fluorine atoms can offer the low-lying LUMO and HOMO energy level and narrow bandgap.^{15,32-40} Therefore, DFBT-containing polymers have high air-stability and high light-harvesting ability. Second, since a DFBT core can facilitate the intra- and intermolecular non-covalent interactions such as N...H, F...S, and F···H between neighboring aromatic π -spacer or polymer backbones, DFBT-based copolymers have high coplanarity with dihedral angles of nearly 0° and can promote the π -orbital overlap between polymer backbones, which can provide a strong aggregation.^{35,41,42} Indeed, it is reported that simple DFBT-quaterthiophene copolymers (PffBT4T-R, Figure 1a) exhibited strong temperature-dependent aggregation.^{15,33,34,43} Moreover, this strong aggregation behavior can facilitate the high crystalline thin films, resulting in a high field-effect hole mobility of nearly 2 cm² V⁻¹ s⁻¹.³³ In addition, since DFBT copolymers also formed the long-range ordered structure even

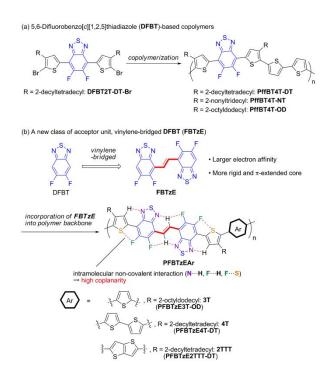
In order to obtain the high-performance low-bandgap p-type

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⁺ Electronic Supplementary Information (ESI) available: Full characterizations, and ¹H, ¹³C{¹H}, and ¹⁹F{¹H} NMR spectra of all new compounds and polymers, details of theoretical calculations, GPC traces, physicochemical properties, SCLC hole mobility, photovoltaic properties, GIWAXS analysis. See DOI: 10.1039/x0xx00000x



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Figure 1 Chemical structures of DFBT, FBTzE, and its copolymers.

in the blended films with soluble fullerene, space-charge limited current (SCLC) hole mobility reached 10^{-2} cm² V⁻¹ s⁻¹, and thus the fabricated OPV exhibited excellent PCE of nearly 12%.^{15,43}

However, to the best our knowledge, despite these excellent features, a new type of DFBT-containing acceptor units have not been developed. Therefore, the development of a new class of acceptor unit bearing a DFBT unit is highly important to develop the novel high-performance semiconducting polymers for OFETs and OPVs.

In terms of the new high-performance p-type and n-type semiconductors based on a DFBT unit, we newly designed and synthesized vinylene-bridged **DFBT** unit (**FBTzE**, Figure 1b). The presence of two DFBT units in the FBTzE core might enhance the electron affinity, which can lower HOMO and LUMO energy levels. In fact, the DFT calculation revealed that model compound of FBTzE-quaterthiophene copolymer has lower HOMO and LUMO energy levels than those of a DFBT counterpart (Figure S1). This feature is highly advantageous for high-performance OPVs and n-type semiconductors. In addition, more rigid and π -extended structure of the FBTzE core owing to various intramolecular non-covalent interaction can enhance the effective π -orbital overlaps, compared to those of DFBT-based polymers, which may lead to the construction of high crystalline thin-film with longer-range ordered structure.²⁸ Herein, we report the synthesis of three bis(4alkylthienyl)FBTzE monomers and the three copolymers containing thiophene, bithiophene, and thienothiophene as the In addition, their physicochemical spacers (Figure 1b). properties, thin-film structure analyses, and solar cell characteristics were investigated to evaluate the potential of **FBTZE** for high-performance semiconducting polymers. Here, each **FBTZE** and bis(4-methylthienyl)**FBTZE** has four possible conformations. From DFT calculations, conformers 1 and 5 is the most thermodynamically stable structure (Figure S2). Thus, we hereafter describe chemical structures of **FBTZE**-based copolymers with these conformations.

Experimental

General

All the reactions were carried out under an Ar atmosphere using standard Schlenk techniques. Glassware was dried in an oven (130 °C) and heated under reduced pressure prior to use. Dehydrated tetrahydrofuran (THF), dimethylsulfoxide (DMSO), and toluene were purchased from Kanto Chemicals Co., Ltd. For thin layer chromatography (TLC) analyses throughout this work, Merck precoated TLC plates (silica gel 60 GF₂₅₄, 0.25 mm) were used. Silica gel column chromatography was carried out using Silica gel 60 N (spherical, neutral, 40-100 µm) from Kanto Chemicals Co., Ltd. The ¹H, ¹³C{¹H}, ¹⁹F{¹H} NMR spectra were recorded on a Varian 400-MR (400 MHz) and Varian INOVA-600 (600 MHz) spectrometer. Infrared spectra were recorded on a Shimadzu IRPrestige-21 spectrophotometer. Elemental analyses were carried out with a Perkin-Elmer 2400 CHN elemental analyzer at Okayama University. Polymerizations were performed with a Biotage initiator microwave reactor. Molecular weights of polymers were determined by gelpermeation chromatography (GPC) with a TOSOH HLC-8321GPC/HT and TSKgel GMH_{HR}-H HT using a polystyrene standard and o-dichlorobenzene (o-DCB) as the eluent at 140 Recycling preparative high performance liquid °C. chromatography (HPLC) was performed on a Shimadzu LC-20AP instrument equipped with Shodex GPC K-4001L and -4002L columns, and Shimadzu RID-10 refractive index detector. Chloroform was used as the mobile phase at room temperature with a flow rate 14 mL min⁻¹.

4-Bromo-5,6-difluorobenzo[c][1,2,5]thiadiazole (1),⁴⁴ 2-bromo-3-(2-hexyldecyl)thiophene (4a),45 2-bromo-3-(2octyldodecyl)thiophene (4b),45 2-bromo-3-(2-(**4c**),⁴⁶ decyltetradecyl)thiophene 2.5bis(trimethylstannyl)thiophene (6),47 5,5'-bis(trimethylstannyl)-2,2'-bithiophene (7)⁴⁸, 2,5-bis(trimethylstannyl)thieno[3,2-**(8)**⁴⁹, *b*]thiophene 5,6-difluorobenzo[c][1,2,5]thiadiazole (DFBT)38, 5,6-difluoro-4,7-bis(5-bromo-4-(2decyltetradecyl)thiophen-2-yl)benzo[c][1,2,5]thiadiazole (DFBT2T-DT-Br, 15)³⁸, and PffBT4T-DT⁴³ were synthesized according to the reported procedures. All other chemicals were used without further purification unless otherwise indicated.

(*E*)-1,2-Bis(5,6-difluorobenzo[*c*][1,2,5]thiadiazol-4-yl)ethene (FBTZE) (3). To a deaerated solution of 4-bromo-5,6difluorobenzo[*c*][1,2,5]thiadiazole (1, 1.18 g, 4.7 mmol) and *trans*-1,2-bis(tributylstannyl)ethylene (2, 1.30 g, 2.1 mmol) in anhydrous toluene (105 mL) in a 200 mL two-necked roundbottomed flask was added tris(dibenzylideneacetone)dipalladium(0)-chloroform adduct

(Pd₂(dba)₃·CHCl₃, 110 mg, 0.11 mmol) and tri(o-tolyl)phosphine (P(o-tolyl)₃, 130 mg, 0.43 mmol). The reaction mixture was heated to a gentle reflux for 12 h. The resulting mixture was cooled to room temperature and added 1 M potassium fluoride (KF) aqueous solution (100 mL). The crude mixture was extracted with chloroform (100 mL × 5) and washed with brine and dried over MgSO₄. After the removal of the solvent under reduced pressure, obtained solid was washed with hexane and purified by passing through pad of Florisil with chloroform as the eluent to afford 3 (772 mg, 2.1 mmol), quantitatively, as a yellow solid. Mp 255-256 ºC. FT-IR (KBr, cm⁻¹): 3107 (w), 3074 (w), 1528 (m), 1466 (s), 1350 (m), 1308 (s), 1182 (s), 974 (s), 937 (m), 872 (s), 843 (s), 438 (m). ¹H NMR (600 MHz, CDCl₃, rt): δ 7.71 (t, J = 8.4 Hz, 2H), 8.88 (s, 2H). ¹³C{¹H} NMR (151 MHz, CDCl₃, rt): δ 105.50, 116.74, 125.46, 149.86, 151.03, 152.41, 154.93. ¹⁹F{¹H} NMR (376 MHz, CDCl₃, rt): δ –130.82 (dd, J = 8.8, 7.5 Hz), -127.84 (dd, J = 7.5, 9.6 Hz). Anal. Calcd for C₁₄H₄F₄N₄S₂: C, 45.65; H, 1.09; N, 15.21%. Found: C, 45.70; H, 0.88; N, 15.20%. Typical Procedure for the Synthesis of (E)-1,2-bis(7-(5-bromo-4-(2-octyldodecyl)thiophen-2-yl)-5,6-

difluorobenzo[c][1,2,5]thiadiazol-4-yl)ethene (5a). In a 50 mL Schlenk tube, 2-bromo-3-(2-hexyldecyl)thiophene (4a, 1.79 g, 4.6 mmol) was added to a mixture of compound 3 (423 mg, 1.15 mmol), palladium(II) trifluoroacetate (Pd(tfa)₂, 77 mg, 0.23 mmol), and silver(I) carbonate (Ag₂CO₃, 2.54 g, 9.2 mmol) in DMSO (25 mL). The reaction mixture was stirred at 140 °C for 24 h. After cooling to room temperature, the mixture was extracted with dichloromethane (50 mL × 3), washed with 1 M HCl aqueous solution and brine, and then dried over MgSO₄. After the removal of the solvent under reduced pressure, obtained solid was purified by silica gel chromatography with hexane and hexane-dichloromethane (5:1) as the eluents ($R_{\rm f}$ = 0.41) to afford 5a (663 mg, 0.58 mmol) in 51% yield as a red solid. Mp 88-90 °C. FT-IR (KBr, cm⁻¹): 2924 (s), 2853 (s), 1541 (m), 1489 (m), 1445 (s), 1354 (m), 982 (m), 851 (m), 536 (m). ¹H NMR (600 MHz, CDCl₃, rt): δ 0.89 (t, J = 7.2 Hz, 12H), 1.20-1.40 (m, 64H), 1.67 (m, 2H), 2.42 (d, J = 7.2 Hz, 4H), 7.70 (s, 2H), 8.10 (s, 2H). ¹³C{¹H} NMR (150 MHz, CDCl₃, rt): δ 14.30, 22.84, 26.69, 29.57, 29.86, 29.93, 30.26, 32.11, 33.48, 34.09, 38.67, 112.15, 113.83, 116.06, 123.40, 131.24, 132.44, 141.75, 148.55, 148.99, 150.05, 152.45. ¹⁹F{¹H} NMR (376 MHz, CDCl₃, rt): δ –130.62 (d, J = 14.7 Hz), -128.54 (d, J = 14.7 Hz). Anal. Calcd for C₅₄H₇₀Br₂F₄N₄S₄: C, 56.93; H, 6.19; N, 4.92%. Found: C, 56.98; H, 6.15; N, 4.87%.

(E)-1,2-bis(7-(5-bromo-4-(2-decyltetradecyl)thiophen-2-yl)-

5,6-difluorobenzo[c][1,2,5]-thiadiazol-4-yl)ethene (5b). Red solid. Yield: 45% (hexane:dichloromethane = 5:1 as the eluents, R_f = 0.70). Mp 73–75 °C. FT-IR (KBr, cm⁻¹): 2924 (s), 2853 (s), 1543 (m), 1489 (m), 1443 (s), 1354 (m), 984 (m), 851 (m), 536 (m). ¹H NMR (600 MHz, CDCl₃, rt): δ 0.87 (t, J = 6.9 Hz, 12H), 1.20-1.40 (m, 64H), 1.71 (m, 2H), 2.50 (d, J = 7.2 Hz, 4H), 7.82 (s, 2H), 8.43 (s, 2H). ¹³C{¹H} NMR (100 MHz, CDCl₃, rt): δ 14.33, 22.92, 26.65, 29.62, 29.96, 30.34, 32.15, 33.35, 33.82, 38.60, 111.56, 112.98, 116.17, 122.02, 131.01, 131.79, 141.33, 147.44, 148.18, 149.91, 152.39. ¹⁹F{¹H} NMR (376 MHz, CDCl₃, rt): δ –130.54 (d, J = 14.7 Hz), –128.61 (d, J = 14.7 Hz). Anal. Calcd for

C₆₂H₈₆Br₂F₄N₄S₄: C, 59.51; H, 6.93; N, 4.48%. Found: C, 59.51; H, 6.96; N. 4.39%.

(E)-1,2-bis(7-(5-bromo-4-(2-decyltetradecyl)thiophen-2-yl)-

5,6-difluorobenzo[c][1,2,5]-thiadiazol-4-yl)ethene (5c). Red solid. Yield: 45% (hexane:dichloromethane = 5:1 as the eluents, $R_f = 0.80$). Mp 62–64 °C. FT-IR (KBr, cm⁻¹): 2924 (s), 2851 (s), 1543 (m), 1489 (m), 1443 (s), 1354 (m), 1342 (m), 1005 (m), 982 (m), 851 (m), 721 (m), 536 (m). ¹H NMR (400 MHz, CDCl₃, rt): δ 0.87 (t, J = 6.8 Hz, 12H), 1.20-1.40 (m, 80H), 1.73 (s, 2H), 2.54 (d, J = 7.2 Hz, 4H), 7.89 (s, 2H), 8.61 (s, 2H). ¹³C{¹H} NMR (151 MHz, CDCl₃, rt): δ 14.32, 22.91, 26.67, 29.63, 29.93, 29.98, 30.00, 30.36, 32.16, 33.37, 33.85, 38.61, 111.62, 113.08, 116.17, 122.16, 131.04, 131.86, 141.38, 147.50, 148.08, 148.42, 149.97, 152.46. Anal. Calcd for C₇₀H₁₀₂Br₂F₄N₄S₄: C, 61.66; H, 7.54; N, 4.11%. Found: C, 61.67; H, 7.76; N, 4.09%.

Typical Procedure for the Synthesis of Polymers (PFBTzE3T-OD, 3T). Monomers 5b (62.6 mg, 0.05 mmol), 2,5bis(trimethylstannyl)thiophene (6, 20.5 mg, 0.05 mmol), tetrakis(triphenylphosphine)palladium(0) (Pd(PPh₃)₄, 1.2 mg, 2 μmol), copper iodide(I) (Cul, 1.0 mg, 5 μmol) and toluene (2.5 mL) were added to a reaction vessel, which was sealed and refilled with argon. The reaction mixture was heated at 180 °C for 2 h in a microwave reactor. After being cooled to room temperature, the reaction mixture was poured into 100 mL of methanol containing 5 mL of concentrated hydrochloric acid and stirred for 3 h. The precipitate was then subjected to sequential Soxhlet extraction with methanol, hexane, and chloroform to remove low molecular-weight fractions. The residue was extracted with chlorobenzene, and concentrated solution was poured into 50 mL of methanol. The formed precipitates were collected by filtration and dried in vacuo to afford 3T (44.7 mg, 76%) as a metallic purple solid. GPC (o-DCB, 140 °C): M_n = 46.9 kDa, M_w = 93.1 kDa, PDI = 1.98. Anal. Calcd for $C_{66}H_{90}F_4N_4S_5$: C, 67.42; H, 7.72; N, 4.77%. Found: C, 66.86; H, 7.52; N, 4.61%.

PFBTzE4T-DT, 4T. Monomers **5c** (68.2 mg, 0.05 mmol), 5,5'bis(trimethylstannyl)-2,2'-bithiophene (**7**, 24.6 mg, 0.05 mmol), tetrakis(triphenyl-phosphine)palladium(0) (1.2 mg, 2 µmol), and toluene (2.5 mL) were subjected to the polymerization procedure, and the reaction mixture was heated at 140 °C for 30 min in a microwave reactor. Sequential Soxhlet extraction with the same solvents used for **3T** was employed to obtain **4T** (40.6 mg, 59%) as a metallic purple solid. GPC (*o*-DCB, 140 °C): $M_n = 133.8$ kDa, $M_w = 319.8$ kDa, PDI = 2.39. Anal. Calcd for $C_{78}H_{108}F_4N_4S_6$: C, 68.38; H, 7.95; N, 4.09%. Found: C, 68.37; H, 8.01; N, 3.94%.

PFBTzE2TTT-DT, **2TTT**. Monomers **5c** (68.2 mg, 0.05 mmol), 2,5bis(trimethylstannyl)thieno[3,2-*b*]thiophene (**8**, 23.3 mg, 0.05 mmol), tetrakis(triphenyl-phosphine)palladium(0) (1.2 mg, 2 μ mol), and toluene (2.5 mL) were subjected to the polymerization procedure, and the reaction mixture was heated at 140 °C for 30 min in a microwave reactor. Sequential Soxhlet extraction with the same solvents used for **3T** was employed to obtain 2T**TT** (39.9 mg, 59%) as a metallic purple solid. GPC (*o*-DCB, 140 °C): M_n = 76.4 kDa, M_w = 166.7 kDa, PDI = 2.18. Anal. Calcd for C₇₆H₁₀₆F₄N₄S₆: C, 67.91; H, 7.95; N, 4.17%. Found: C, 67.65; H, 7.95; N, 3.92%.

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Instrumentation and Theoretical Calculation

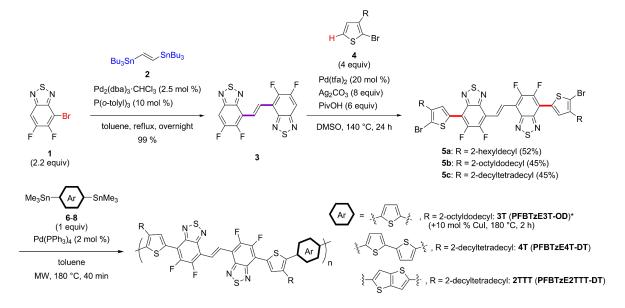
UV-vis absorption spectra were measured using a Shimadzu UV-2450 UV-vis spectrometer. Cyclic voltammograms (CVs) were recorded on Electrochemical Analyzer CHI-600B in acetonitrile containing tetrabutylammonium hexafluorophosphate (TBAP, 0.1 M) as supporting electrolyte at a scan rate of 100 mV/s. A Pt electrode (surface area: $A = 0.071 \text{ cm}^2$, BAS), an Ag/Ag⁺ (Ag wire in 0.01 M AgNO₃/0.1 M TBAPF₆/CH₂Cl₂ or CH₃CN), and a Pt wire electrode were used as working, reference, and counter electrodes, respectively. Samples of the polymer films were prepared by drop-casting on a working electrode from their chloroform solutions. All the potentials were calibrated with the standard ferrocene/ferrocenium redox couple (Fc/Fc⁺: $E^{1/2}$ = +0.52 V for CH_2CI_2 , and $E^{1/2}$ = +0.01 V for CH_3CN measured under identical conditions). Dynamic force-mode atomic force microscopy was carried out using an SPA 400-DFM (SII Nano Technologies). Grazing incidence wide-angle X-ray diffraction (GIWAXS) analyses were carried out at SPring-8 on beamline BL46XU. The samples were irradiated at a fixed angle on the order of 0.12° through a Huber diffractometer with an X-ray energy of 12.39 keV (λ = 1 Å), and the GIWAXS patterns were recorded on a 2D image detector (Pilatus 300K). Films of the polymers and blended films with $\mathsf{PC}_{61}\mathsf{BM}$ were fabricated by spin-coating on the ZnO treated ITO substrate. Geometry optimizations and normal-mode calculations were performed at the B3LYP/6-31G(d) or M06-2X/6-31G** level using the Gaussian 09, Revision D.01, program package.⁵⁰

Fabrication of Inverted Bulk-heterojunction Solar Cells

The inverted bulk-heterojunction solar cells were fabricated as follows. ZnO precursor solution was prepared by hydrolysis of $Zn(OAc)_2$.⁵¹ The ITO substrates (ITO, Geomatec Co. Ltd., thickness = 150 nm, sheet resistance < 12 Ω sq⁻¹, transmittance (λ = 550 nm) \geq 85%) were successively washed using

ultrasonication in a neutral detergent, deionized water, acetone, and isopropanol at room temperature, and in hot isopropanol, for 10 min, respectively. Then ITO substrates were treated with UV-ozone for 20 min. Pre-cleaned ITO substrates were spin-coated with 0.4 M ZnO precursor solution at 4000 rpm for 30 sec, and then immediately baked at 200 °C for 30 min in air. After gradual cooling to room temperature, the substrates were rinsed with acetone and isopropanol at room temperature, then in hot isopropanol for 5 min. The substrates were dried and immediately transferred into a nitrogen-filled glove box. The active layers with PC₆₁BM were deposited by spin-coating (at 600 rpm for 60 sec for 3T, and at 600 rpm for 30 sec for 4T and 2TTT) from a solution containing a polymer sample (10.0 mg/mL for 3T, 3.3 mg/mL for 4T, and 6.0 mg/mL for 2TTT) and a respective amount of PC₆₁BM in anhydrous chlorobenzene (CB). The solution was kept at 100-140 °C (100 °C for **3T**, and 140 °C for **4T** and **2TTT**) for 30 min, and the hot solution was spin-coated on the substrate (at room temperature for 3T, and preheated at 140 °C for 4T and 2TTT before spin-coating). p/n Ratio is weight ratios of polymers and PC₆₁BM. 1,8-Diiodooctane (DIO, 1 vol% for 4T) or diphenyl ether (DPE, 2.5 vol% for 3T and 4 vol% for 2TTT) were used as the solvent additives. The active layer thickness of 3T, 4T, and 2TTT was 100-130 nm, respectively. The uniform 4T/PC₆₁BM blended film could not be obtained, due to too strong aggregation tendency of 4T. MoO₃ (6 nm) as an anode interlayer and an Ag (50 nm) layer were deposited under high vacuum ($\sim 6 \times 10^{-5}$ Pa) through a shadow mask. The active area of all devices was 0.16 cm². The thickness of the active layer was measured with an AlphaStep® IQ surface profiler (KLA Tencor).

The characteristics of the solar cell devices were measured through a 4 \times 4 mm photo-mask, with a Keithley 2401 semiconductor analyzer, using a Xe lamp (Bunkokeiki OTENTO-SAN III type G2) as the light source, under AM 1.5 G simulated solar irradiation at 100 mWcm⁻² at room temperature under a



Scheme 1 Synthesis of FBTzE 3, monomers 5a-5c, and Copolymers.

nitrogen atmosphere. The light intensity was determined by a calibrated standard silicon solar cell (Bunkokeiki, BS-520BK). External quantum efficiency (EQE) was measured using a Bunkokeiki SM-250 Hyper Monolight System.

Fabrication and Characterization of Hole-only Devices

Hole-only devices were fabricated as follows. ITO substrates were washed and treated with UV-ozone in the same manner as described above. Then, ITO substrates were spin-coated with poly(3,4-ethylene-dioxythiophene):poly(styrene sulfonate) (PEDOT:PSS) (Clevios P VP AI 4083) through a 0.45 μm PVDF syringe filter at 5000 rpm for 30 sec, and dried at 120 °C for 10 min in air. After being dried, the substrates were immediately transferred into a nitrogen-filled glove box. Thin films of an active layer were deposited by same procedure as described above (high concentration solution was used, 13.3 mg/mL for 3T and 8.0 mg/mL for 2TTT). The active layer thickness of **3T** and **2TTT** was 240 and 220 nm, respectively. After the thin films were dried, MoO₃ (6 nm) and Al (80 nm) layers with an active cathode area of 0.16 cm² were deposited under high vacuum ($\sim 6 \times 10^{-5}$ Pa) through a shadow mask.

Current density-voltage (*J*-*V*) characteristics of the fabricated devices were measured using a Keithley 2401 Source Meter in the dark. Voltage sweeps were performed in the range of 0-8 V, and hole mobilities were estimated from the *J*-*V* curve of the Mott-Gurney space charge limited current (SCLC) law:⁵²

$$J = (9/8) \varepsilon_0 \varepsilon_r \mu (V^2/L^3)$$
(1)

where ε_0 is the permittivity of free space, ε_r is the dielectric constant of the polymer, μ is the hole mobility, L is the thickness of the active layer, and V is the voltage drop across the device ($V = V_{appl} - V_{bi}$). ε_r is assumed to be 3, which is a typical value for semiconducting polymers.

Results and Discussion

Synthesis of FBTzE Derivatives and FBTzE-Based Copolymers PFBTzEAr

Scheme 1 shows synthetic routes of FBTzE 3, monomers 5a-5c, and three copolymers. Migita-Kosugi-Stille coupling of 4bromo-5,6-difluorobenzo[c][1,2,5]thiadiazole (1)⁴⁴ and trans-1,2-bis(tributylstannyl)ethylene (2) afforded FBTzE 3 in 99% yield. Then, FBTzE-containing monomers 5a-5c were synthesized by dehydrogenative coupling of 3 with 2-bromo-3-(2-alkyl)thiophenes 4a-4c.44,53,54 After optimization of the palladium catalyst, oxidant, and additive, we could obtain compound 5a in 52% isolated yield (Table S1). Accordingly, with the same reaction conditions in hand, monomers **5b** and **5c** with different side chains were also synthesized. When 5a was used for copolymerization with distannylated bithiophene 7, soluble polymers were not obtained due to its insufficient solubility. Therefore, Migita-Kosugi-Stille coupling reactions of 5b with distannylated thiophene 6, and of 5c with distannylated bithiophene 7 and -thienothiophene 8 yielded three copolymers **PFBTzEAr** in 76% (**Ar** = **3T**), 59% (**Ar** = **4T**), and 59% (Ar = 2TTT), respectively. In the case of 3T, the addition of Cul and longer time were needed to obtain high-molecular-weight

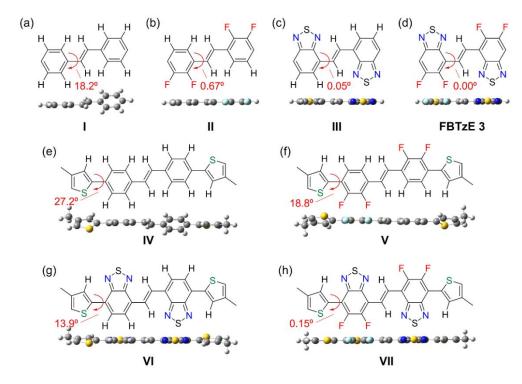


Figure 2 The optimized molecular structures and calculated dihedral angles of model compounds by DFT using M06-2X/6-31G** level.

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 Table 1 Physicochemical Properties of P-PDT-DFBO

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compound	$\lambda_{\max, \text{ sol}}/\mathrm{nm}^a$	$\lambda_{ ext{max, film}}/ ext{nm}^{b}$	$E_{g}^{opt} (E_{g}^{CV})/eV^{c}$	E _{HOMO} /eV ^d	E _{LUMO} /eV ^e	
3	385	-	2.80 (2.94)	-6.20	-3.26	
5b	483, 506	-	2.16 (2.29)	-5.69	-3.40	
5c	483, 506	-	2.13 (2.28)	-5.68	-3.40	
ЗТ	629, 693	632, 685	1.56 (1.74)	-5.45	-3.71	
4T	643, 704	636, 698	1.55 (1.64)	-5.33	-3.69	
2TTT	648, 708	644, 707	1.54 (1.64)	-5.35	-3.71	
DFBT	307	-	3.71 (3.05)	-6.03	-2.98	
DFBT2T-DT-Br	317, 452	-	2.34 (2.40)	-5.71	-3.31	
PffBT4T-DT	599, 695 (549)	637, 698	1.58 (1.63)	-5.25	-3.62	

^{*a*}Absorption maxima in dichloromethane or chlorobenzene solution at rt. ^{*b*}Absorption maxima in thin film. ^{*c*}Optical energy gap estimated from absorption edge (λ_{edge}) (out of parentheses) and electrochemical gap (in parentheses). ^{*d*}All the potentials were calibrated with the standard ferrocene/ferrocenium redox couple (Fc/Fc⁺: $E^{1/2} = +0.52$ V for CH₂Cl₂ (small molecules), and $E^{1/2} = +0.01$ V for CH₃CN (polymer) measured under identical conditions). Estimated with the oxidation onset vs Ag/Ag⁺; $E_{HOMO} = -4.28$ or $-4.79 - E^{ox}_{onset}$. ^{*e*}Estimated with the reduction onset vs Ag/Ag⁺; $E_{LUMO} = -4.28$ or $-4.79 - E^{ox}_{onset}$.

polymer. From high-temperature gel-permeation chromatography (GPC) analyses, all three polymers have high molecular weight over 40 kDa. Among them, the numberaverage molecular weight (M_n) of **4T** and **2TTT** polymers $(M_n =$ 133.8 and 76.4 kDa) are significantly higher than that of $3T (M_n$ = 46.9 kDa). This result might be attributed to the high aggregation in the solution. In fact, GPC curves of 4T and 2TTT showed obvious dual peaks at high and low retention time region, and $M_{\rm p}$ of the polymer obtained from a lowconcentration solution of 4T and 2TTT become a lower value than that from high-concentration solution (Figure S5, Table S2). Therefore, polymers 4T and 2TTT have stronger intermolecular interaction, likely due to their higher symmetry of polymer backbones.55

Computational Study of FBTzE and Its Derivatives

In order to evaluate the non-covalent intermolecular interaction, the optimized structures of several model compounds were calculated by density functional theory (DFT) using M06-2X/6-31G** level.³⁵ Figure 2 shows the optimized structure and dihedral angle of non-substituted and fluorinated trans-stilbenes, vinylene-bridged benzothiadizoles, and FBTzE derivatives. trans-Stilbene (I) has a large dihedral angle of 18.2° between benzene rings and a vinylene moiety owing to a steric repulsion of each hydrogen atom (Figure 2a). On the other hand, by introducing fluorine atoms or a fused thiadiazole ring instead of two hydrogen atoms, the dihedral angles of fluorinated *trans*-stilbene (II) and vinylene-bridged benzothiadizole (III) were drastically decreased to 0.67° and 0.05°, respectively (Figure 2b,c). This suggests that N···H or F···H interaction can increase the coplanarity of a FBTzE framework. Especially, N···H can provide the higher coplanarity than that of F...H, likely due to the existence of stronger hydrogen bond. Furthermore, FBTzE 3 with both thiadiazole ring has a completely coplanar structure with a dihedral angle of 0° (Figure 2d). In thiophene-containing compounds, bisthienyltrans-stilbene (IV) also has a large dihedral angle of 27.2° between benzene and adjacent thiophene rings (Figure 2e). On

the other hand, model compounds **V** and **VI** have largely decreased dihedral angles of 18.8° and 13.9°, respectively, but they do not have completely planar structures (Figure 2f,g). In contrast, the dihedral angle of bisthienyl **FBTzE** (**VII**) is less than 1°, indicating that both N···H and F···S interactions are required to afford the completely planar structure (Figure 2h). These N···H and F···S interactions between benzothiadiazole derivatives and neighboring thiophene ring is well-known and evaluated by single-crystal structure analyse.^{42,56,57} These calculation results are consistent with previously reported

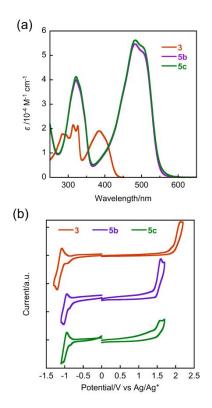


Figure 3 (a) UV-vis absorption spectra and (b) cyclic voltammograms of 3 and monomers 5b and 5c in CH_2CI_2 solution.

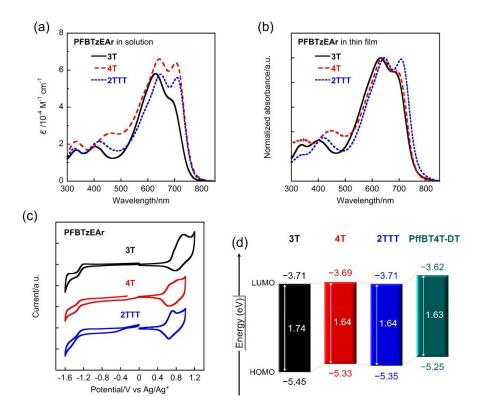


Figure 4 UV-vis absorption spectra in solution (a) and in thin film (b). (c) Cyclic voltammograms in thin film of polymers **3T**, **4T**, and **2TTT** and (d) their energy diagrams.

results. From these results, highly coplanar structure of **FBTzE** and its derivative can be expected to give the densely packing structure in the solid state.

Physicochemical Properties of FBTzE Derivatives

UV-vis absorption spectra and cyclic voltammograms of 3 and monomers 5b and 5c are shown in Figure 3a,b, and the results are summarized in Table 1, comparing the physicochemical properties of the standard DFBT and DFBT monomer (DFBT2T-**DT-Br**, Figure 1a) (Figures S6a,b). The UV-vis absorption spectrum of 3 showed the absorption maximum at 385 nm, which is 78 nm red-shifted absorption than that of DFBT. In addition, the optical energy gap (E_g) of **3** (2.81 eV) is significantly smaller than that of **DFBT** (3.71 eV), indicating the effective π extension of FBTzE core. In monomers 5b and 5c, the 32 nm red-shifted absorption (483 nm) and about 0.2 eV smaller E_{g} were observed, compared to those of DFBT2T-DT-Br. Furthermore, the absorption coefficients of **5b** and **5c** are ca. 3.5 times higher (\sim 55,000 M⁻¹ cm⁻¹) than that of **DFBT2T-DT-Br**. This results indicates that FBTzE derivatives 5b and 5c have stronger absorption, which is beneficial for solar cells.

The electrochemical properties of **3** and monomers **5b** and **5c** were investigated (Figure 3b, Table 1). **FBTzE 3** exhibited clear one oxidation and reduction waves. The estimated HOMO and LUMO energy level are -6.20 and -3.26 eV, respectively, both of which are lower than that of **DFBT** (HOMO = -6.03 eV and LUMO = -2.98 eV). This indicates that **3** has larger electron affinity due to the existence of two **DFBT** in its core. On the

other hand, **5b** and **5c** have significantly higher HOMO energy levels around –5.7 eV, and their LUMO energy level are slightly lower than that of **3**. From DFT calculations, the coefficient of LUMO in **5b** and **5c** strongly localized on the central **FBTzE** core, but HOMO coefficient delocalized on the entire the molecules (Figure S3). Therefore, the difference of LUMO energy level between **3** and monomers **5b** and **5c** is rather small.⁵⁸ Such tendency is in a good agreement with DFT calculations (Figure S1). Compared to **DFBT2T-DT-Br**, **5b** and **5c** exhibited lower LUMO and similar HOMO energy levels, indicating the π extension of **FBTzE** core, which is consistent with the result of UV-vis absorption spectra.

Physicochemical Properties of FBTzE-based Copolymers, 3T, 4T, and 2TTT

UV-vis absorption spectra of **PFBTzEAr** polymers are depicted in Figures 4a and 4b, and the extracted parameters are summarized in Table 1. Figure S6c also showed absorption spectra of **DFBT**-based polymer **PffBT4T-DT** for the comparison. **4T** has the almost similar E_g (1.55 eV) to that of the representative reported polymer **PffBT4T-DT** (1.58 eV) in the solid state (Figure 4b and S6c). One possible reason for such similar E_g may be a similar effective π -conjugation length. In fact, DFT calculations of their model compounds revealed that the difference of E_g between **4T** and **PffBT4T-DT** decreased with an increase of repeating units (Figure S1). Interestingly, both **4T** and **PffBT4T-DT** showed strong temperature-dependent aggregation, but quite different behaviors were observed (Figure S6c and S7b). Upon heating at ca. 80 °C in solution, 4T exhibited slight blue-shifted spectra and the decrease of an intensity, while PffBT4T-DT showed significantly hypochromic shifted absorption spectrum and one broad absorption at longer wavelength region, indicating that 4T formed partial aggregate in the high temperature solution, whereas PffBT4T-DT showed completely disaggregated behavior. These results suggest that 4T has stronger intermolecular interaction than that of PffBT4T-DT due to its extended $\pi\text{-electron}$ system. Cyclic voltammograms of polymers revealed that 4T have lower HOMO and LUMO energy levels (-5.33 and -3.69 eV) than those of PffBT4T-DT (-5.25 and -3.62 eV) (Figures 4c,d and S6d, Table 1). This may be attributed to a larger electron affinity of the FBTzE core, which are consistent with DFT calculations. Such low-lying HOMO and LUMO energy levels of FBTzE-based polymer are beneficial for the development of highperformance p-type polymers and n-type semiconductors in OPVs.

All the three polymers 3T, 4T, and 2TTT exhibited similar absorption spectra with almost same E_g (Figure 4a,b and Table 1). The intensity in absorption spectra of 4T and 2TTT was significantly decreased (Figure S7 and Table S3). This indicates that polymers 4T and 2TTT have partial aggregation in the hightemperature solution, and thus have a strong intermolecular interaction. In thin film, the absorption spectrum of 2TTT is identical to that of its room-temperature solution, indicating that 2TTT formed the highly ordered packing structure in roomtemperature solution. On the other hand, the absorption spectrum of 4T-based film showed slightly blue-shifted compare to room-temperature solution. One possible reason for such difference may be attributed to the different packing motif in the solid state. Such tendency is also observed in high molecular-weight PffBT4T-DT,³³ but actual reason has not been described. Polymer **3T** has a similar absorption before and after heating. In addition, the spectrum of **3T** in solution at room temperature is almost identical to that in its thin film. This suggests that **3T** seems to form large aggregate even in the hightemperature solution, which is inconsistent with the result of GPC trace. Polymer 3T has a higher solubility and lower viscosity in high concentration solution than that of the other polymers 4T and 2TTT. In addition, 3T showed 10-20 nm blueshifted spectra than that of 4T and 2TTT. From these results, we concluded that **3T** did not form large aggregate in the roomtemperature solution and has weaker intermolecular interactions. One possible reason for such difference among three polymers is their symmetry of the polymer backbones. From DFT calculations of a dimer structure, **3T** formed a twisted backbone due to the steric hindrance between two alkyl side chains onto terthiophene unit, whereas $\mathbf{4T}$ and $\mathbf{2TTT}$ have a relatively coplanar structure owing to their higher regioregularity (Figure S4). Such coplanar structure can enhance the effective $\pi\text{-}\pi$ overlaps, resulting in a stronger aggregation ability. On the other hand, polymer **3T** have 0.1 eV deeper HOMO and same LUMO energy levels as those of polymers 4T and 2TTT (Figure 4c,d and Table 1). This may be attributed to its twisted backbone to diminish the effective π - π

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Table 2 Solar Cell Performances of Polymer/PC ₆₁ BM-based
Devices ^a

device ^b	J _{sc} /mA cm ⁻²	V _{oc} /V	FF	PCE (PCE _{avg})
ЗТ	7.00	0.88	0.43	2.66 (2.60)
2TTT	11.47	0.80	0.57	5.23 (5.09)

^{*a*}Average values are shown in parentheses. ^{*b*}For **3T**, the polymer/PC₆₁BM blend ratio is 1:1 (w/w), solvent = chlorobenzene (CB) + 2.5 vol% diphenyl ether (DPE); For **2TTT**, the polymer/PC₆₁BM blend ratio is 1:2 (w/w), solvent = CB + 4 vol% DPE.

overlap^{59,60} or arising from the terthiophene unit having the reduced electron-donating ability.⁶¹

Photovoltaic Properties of Polymer/PC₆₁BM-Based Solar Cells

To evaluate the potential of **FBTzE** for high-performance electronics, typical inverted solar cells with device structure of ITO/ZnO/(polymer:PC₆₁BM)/MoO₃ (6 nm)/Ag (50 nm) were fabricated and characterized. Typical current density (*J*)-Voltage (*V*) characteristics of the fabricated solar cells under AM 1.5 G simulated solar irradiation at 100 mW cm⁻² are depicted in Figure 5a, and the extracted solar cell parameters are summarized in Table 2 and Table S4. The solar cell based on **4T** did not show photovoltaic response due to the current leakage, because uniform thin-film was not fabricated due to its strong aggregation behavior. The best p/n ratio of **3T** and **2TTT**-based devices were found to be 1:1 and 1:2. The best solar cell performances were obtained, when the substrate temperature is room temperature for **3T** and 140 °C for **2TTT**, respectively.

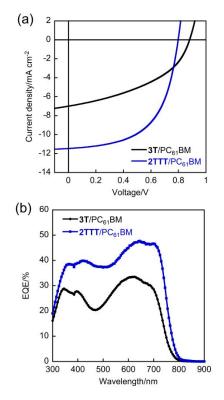


Figure 5 (a) J-V curves and (b) EQE spectra of 3T and $2TTT/PC_{61}BM$ -based solar cells.

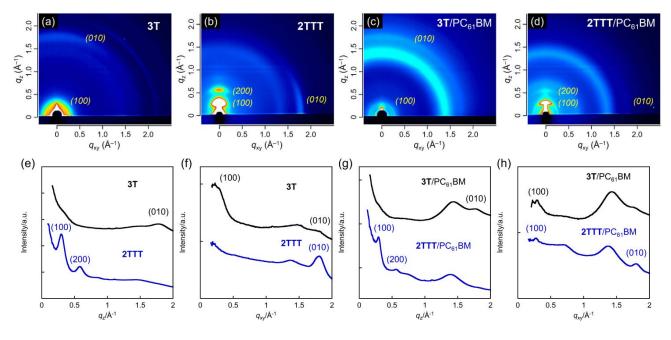


Figure 6 2D GIWAXS images of (a,b) polymer and (c,d) polymer/ $PC_{61}BM$ blended films on ITO/ZnO substrate; (a) **3T**, (b) **3T**/ $PC_{61}BM$ (p/n = 1:1, CB+2.5 vol% DPE), (c) **2TTT**, and (d) **2TTT**/ $PC_{61}BM$ (p/n = 1:2, CB+4 vol% DPE). 1D cross-sectional profiles of (e,f) pure polymer films and (h,g) polymer/ $PC_{61}BM$ blended films on ITO/ZnO substrate; (e,g) out-of-plane and (f,h) in-plane.

Both 3T- and 2TTT-based devices without optimization exhibited poor solar cell performances with PCE of 0.87% (for 3T) and 3.09% (for 2TTT), due to their low short-circuit current density (J_{sc}) and fill factor (FF). When 2.5% and 4% of diphenyl ether (DPE) were used as the solvent additive in 3T and 2TTTbased solar cells, respectively, the best OPV performances were observed. Since **3T** has a deeper HOMO energy level, its solar cell exhibited higher open-circuit voltage (V_{oc}) (0.88 V) than that of 2TTT-based solar cell (0.80 V). However, 2TTT-based cell showed significantly higher J_{sc} (11.47 mA cm⁻²) and FF (0.57) than those of **3T**-based cell (J_{sc} = 7.00 mA cm⁻², FF = 0.43), and thus higher PCE of 5.23%. From EQE spectra, 2TTT-based solar cell has a higher photocurrent conversion with maximum EQE of 48% in all regions, compared to the **3T**-based device (Figure 5b), leading to a high J_{sc} . In order to understand the difference of solar cell performances between **3T** and **2TTT**, the hole-only devices with the device configuration of ITO/(PEDOT:PSS)/(polymer:PC₆₁BM)/MoO₃ (6 nm)/Al (80 nm) were fabricated and characterized to estimate their SCLC hole mobility (Figure S8). However, despite higher FF, SCLC hole mobility of the **2TTT**-based hole-only device ($\mu_h = 5.40 \times 10^{-5}$ cm² V⁻¹ s⁻¹) is lower than that of **3T**-based device (μ_h = 7.66 × 10⁻⁵ cm² V⁻¹ s⁻¹). We speculated that low mobility balance of 3T-based device may lead to low FF, because such mobility balance strongly affects FF of solar cells.⁶²

GIWAXS Measurement and Surface Morphology of Pure Polymer and Polymer/PC₆₁BM Blended Films

In order to evaluate their structure-property relationships, grazing incidence wide-angle X-ray scattering (GIWAXS) and atomic force microscopy (AFM) measurements of

polymer/PC₆₁BM blended films were carried out (Figures 6 and 7, Table S6). In pure polymer films, **3T** film showed weak lamellar diffraction (100) at 0.300 Å⁻¹ in q_{xy} axis and π -stacking diffraction (010) at 1.777 Å⁻¹ in q_z axis (Figure 6a,e,f). From these diffractions, **3T** formed a favorable face-on orientation

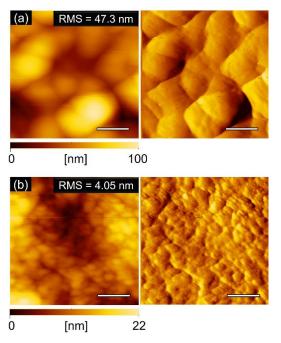


Figure 7 Topological (left) and error-signal (right) images of polymer/PC₆₁BM blended films on ITO/ZnO substrate; (a) **3T**/PC₆₁BM (p/n = 1:1, CB+2.5 vol% DPE), and (b) **2TTT**/PC₆₁BM (p/n = 1:2, CB+4 vol% DPE). Scale bar is 500 nm.

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with short π -stacking distance (d_{π}) of 3.57 Å. In addition, **3T**/PC₆₁BM blended film also formed predominantly face-on orientation with almost same lamellar distance (d_{lm}) of 21.1 Å and short d_{π} of 3.57 Å (Figure 6c,g,h). Although **3T** has favorable molecular orientation in both pure polymer and blended film with PC₆₁BM, it formed large-scale phase separation with the domain size of 300-500 nm (Figure 7a). Such unfavorable phase separation structure must prevent the effective photocurrent generation, leading to a poor $J_{sc.}^{63,64}$ In contrast, **2TTT** exhibited strong lamellar diffraction (100) at 0.298 Å⁻¹ in q_z axis and π stacking diffraction (010) at 1.805 Å⁻¹ in q_{xy} axis, which are completely opposite direction compared to 3T film (Figure 6b,e,f). This indicates that 2TTT formed unsuitable edge-on orientation with a short d_{π} of 3.49 Å. Moreover, **2TTT**/PC₆₁BM blended film also exhibited almost same diffraction patterns with almost same lamellar distance (d_{lm}) of 21.5 Å and short d_{π} of 3.49 Å (Figure 6d,g,h). Such unfavorable orientation may limit the efficient carrier transport, leading to low hole mobility. However, 2TTT/PC61BM blended film formed well-separated phase separation with a smaller domain size (Figure 7b). Therefore, 2TTT-based cell showed higher J_{sc} than that of 3Tbased cell, resulting in a higher PCE.

Conclusions

In summary, we have successfully synthesized FBTzE as a new class of an acceptor unit via Migita-Kosugi-Stille coupling and dehydrogenative coupling. In addition, three FBTzE-based copolymers, 3T, 4T, and 2TTT were also synthesized. FBTzEcontaining compounds showed lower LUMO energy levels and smaller E_g than those of a standard DFBT core, due to its larger electron affinity and π -extended core. In addition, **FBTzE**-based copolymers have lower-lying HOMO and LUMO energy levels, stronger interaction than those of the parent DFBT-based polymer PffBT4T-DT, which are beneficial for high-performance electronics. Among the three polymers, 2TTT-based solar cell exhibited good solar cell performance with PCE of 5.23%, although 2TTT formed unfavorable edge-on orientation with short d_{π} of 3.49 Å. Thus, the **FBTzE** core is a potential building block for high-performance D-A semiconducting polymers. Currently, we are investigating to improve the molecular orientation by optimizing solubilizing side chains and donor units.

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Vinylene-Bridged Difluorobenzo[c][1,2,5]-thiadiazole (FBTzE):

A New Electron-Deficient Building Block for High-Performance Semiconducting Polymers in Organic Electronics

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A new class of an acceptor unit, vinylene-bridged 5,6-difluorobenzothiadiazole **FBTzE**, and three **FBTzE**-containing copolymers has been synthesized and characterized.

